

# 實驗四

## 電光調變器實驗

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# Modulator (調變器)

## 實驗目的

- 了解電光調變器的操作原理及使用方式
  - 在光纖通訊系統中，把要傳送之信號加載到光波上的過程就是調變。
  - 光調變器就是實現從電信號到光信號的轉換的元件。



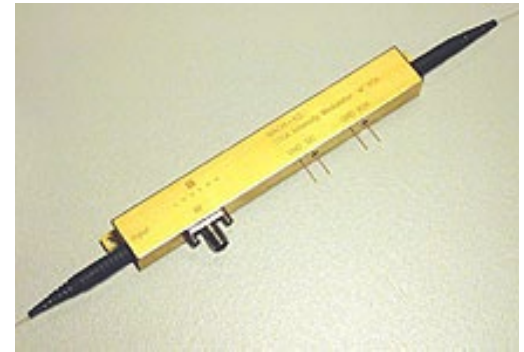
**EA Modulator**

**Electro-absorption**



**AO Modulator**

**Acousto-Optical**

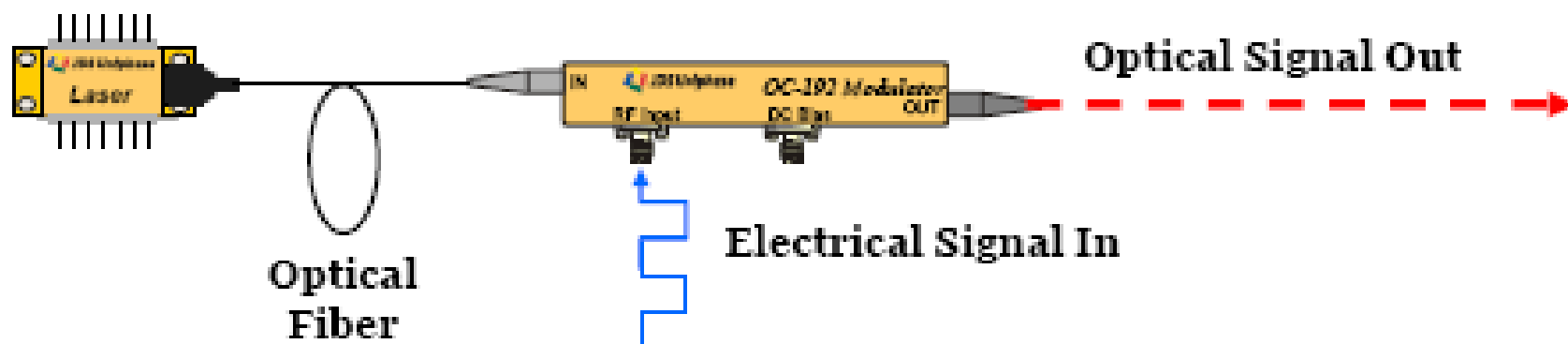


**EO Modulator**

**Electro-optical**

# Modulator (調變器)

## 實驗架構

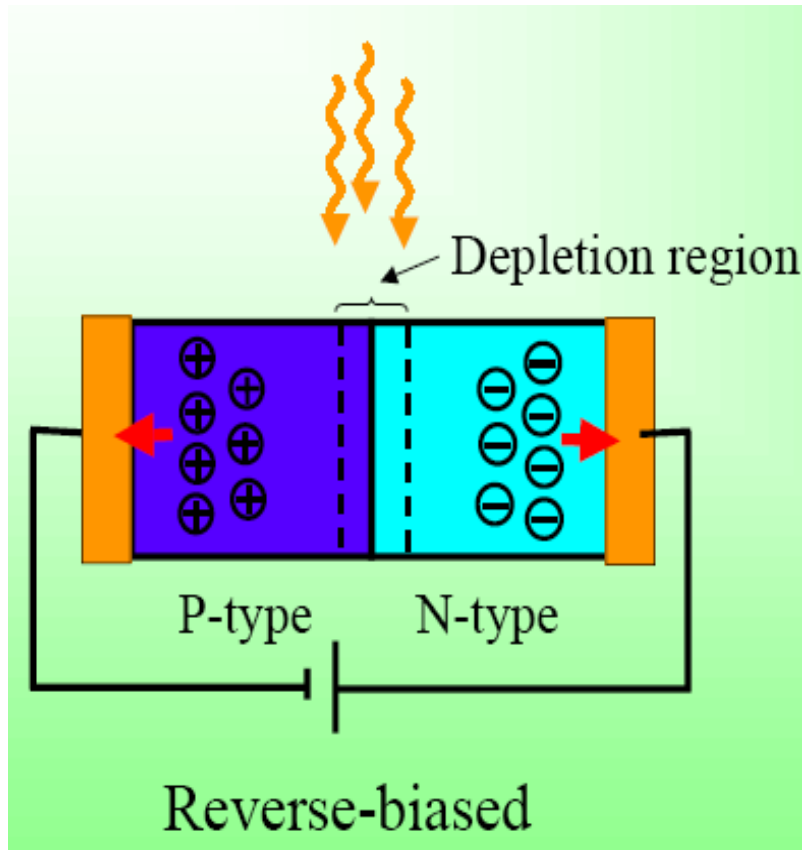


**Laser source**

實驗當中使用：Tunable Laser



# Electro-absorption (EA) modulator



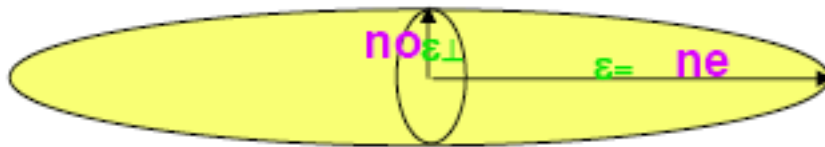
- When the P-N structure in LED is reverse-biased, it becomes light absorption
- At zero-bias, absorption is weak. Under strong reversebiased, absorption is strong.
- Light intensity is then modulated by signal voltage.

<http://ntuee.org/data/photonics/Chapter6.pdf>

# Birefringence (雙折射)

Definition:

- The material has a single axis of **anisotropy**.
- Decomposition of a ray of light into two rays (ordinary ray & extraordinary ray) when it passes through certain types of material.

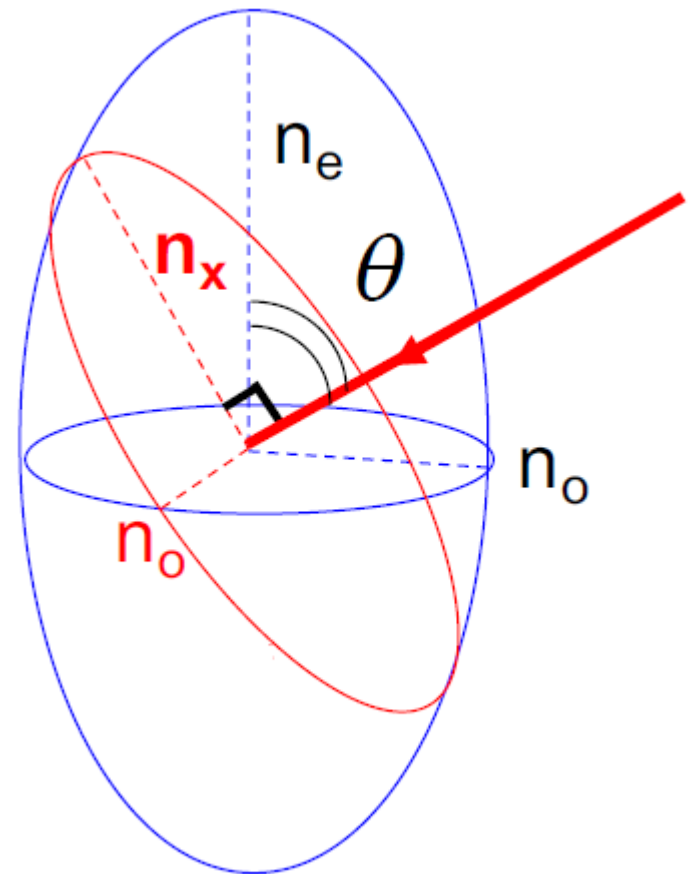


E.g. LC (液晶),  $\text{LiNbO}_3$  (鈮酸鋰)...

# Effective $n_e$

- In general, when light is incident at an angle  $\theta$  relative to the director ( $//$  to  $n_e$ )
- the two refractive indices for the two polarizations are  $n_o$  and  $n_x$ , where  $n_x$  is given by:

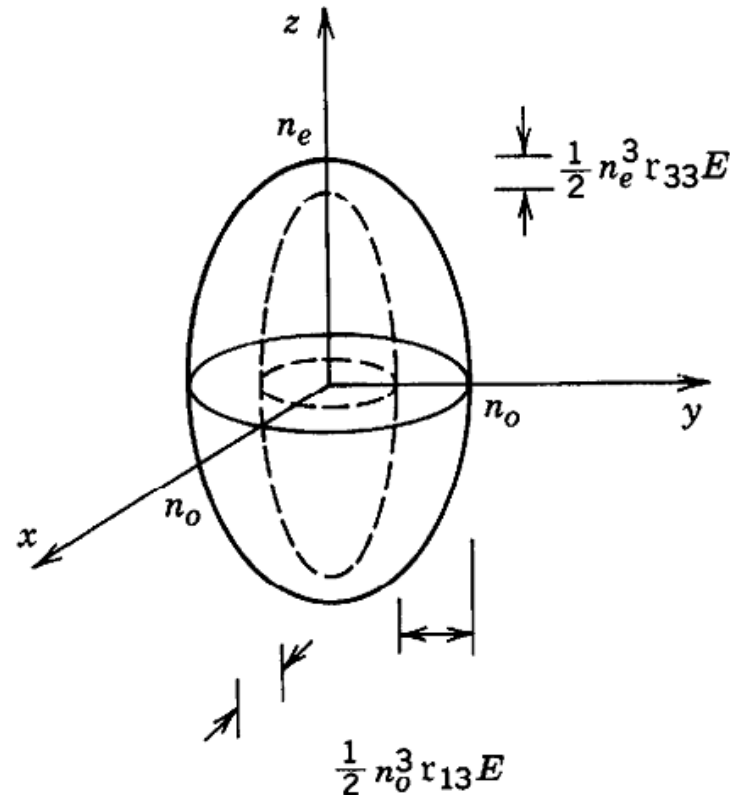
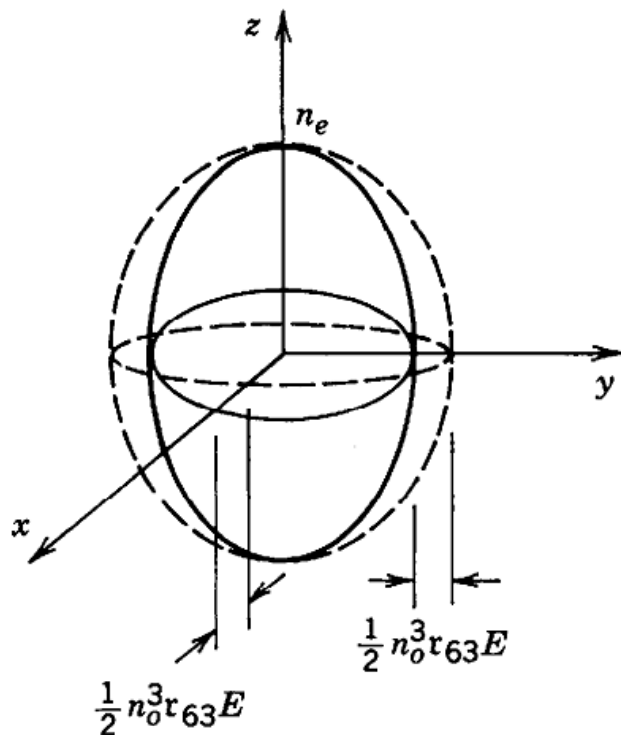
$$n_x(\theta) = n_e(\text{eff}) = \frac{1}{\sqrt{\left(\frac{\cos \theta}{n_o}\right)^2 + \left(\frac{\sin \theta}{n_e}\right)^2}}$$



Intersection plane  $\perp$  to the incident light

# Electro-Optic Effect

- 當外加電場於晶體內部時，晶體的電荷分佈及晶格結構會微量變形



# Electro-Optical Effect (電光效應)

- 外在電場引起電光晶體折射率變化。
- 折射率改變會使得通過晶體的光波傳播特性改變。
- LiNbO<sub>3</sub>
- KH<sub>2</sub>PO<sub>4</sub> (KDP)

Applied Electric Field “E”

Non-linear electric-optical effect <Kerr effect>

$$\left(\frac{1}{n^2}\right) = rE + rE^2$$

**r**：電光晶體上各方向的電光係數

Linear electric-optical effect <Pockels effect>



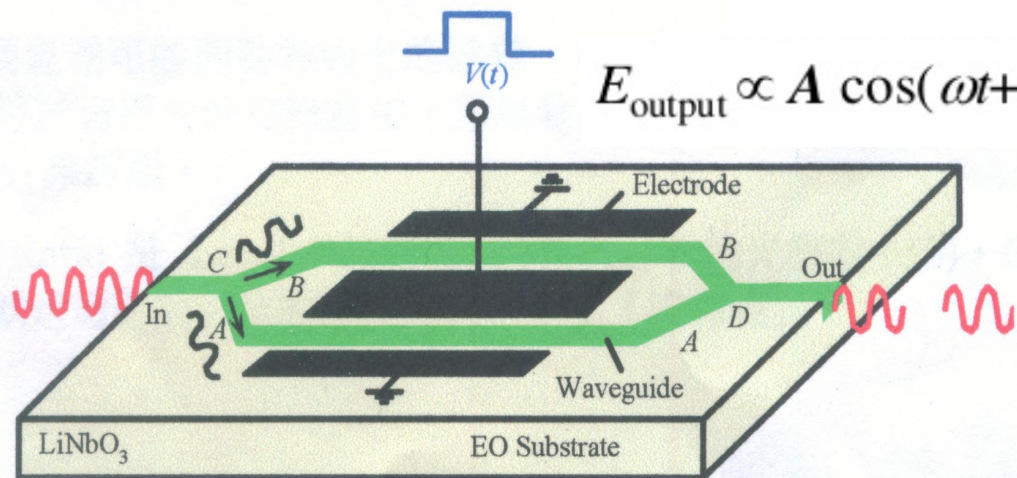
# Electro-Optic (EO) modulator

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- 以積體光學的技術在LiNbO<sub>3</sub>晶片上以光波導的形式製作出Mach-Zehnder干涉儀。
- 在光波導上方製作電極。
- 當電訊號通過電極時所形成的電場會改變光波導的折射率，使得o-ray和e-ray形成光程差，在會合時產生干涉。
- 當電場變化時同時改變干涉結果，即調變合成光波的振幅。

# Optical switching: Mach-Zehnder Modulator

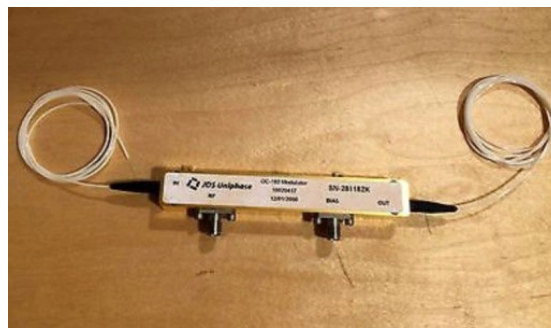
- The input light is split into two coherence wave A and B, which are phase shifted applied voltage, and then two will combine in the output arm.
- The output amplitude depends on the phase difference (optical path) between A and B branches. The output power is proportional to  $E_{\text{output}}^2$



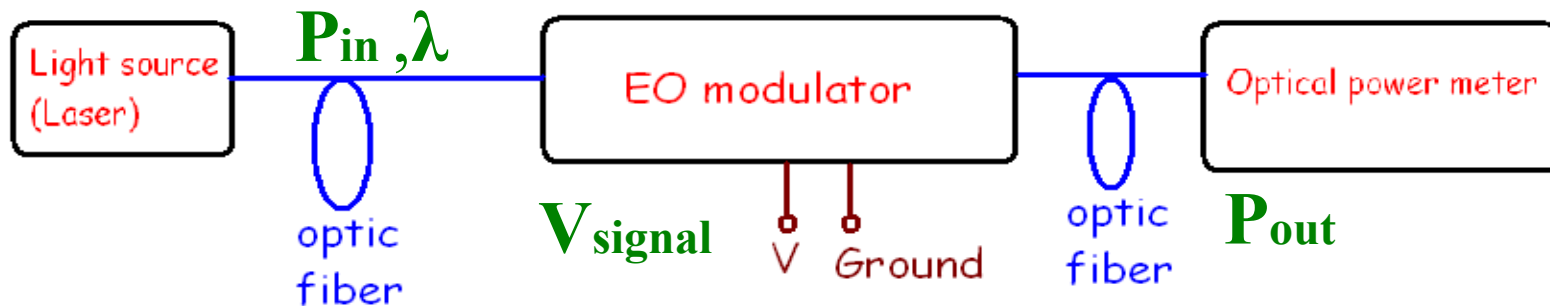
$$E_{\text{output}} \propto A \cos(\omega t + \phi) + A \cos(\omega t - \phi) = 2A \cos \phi \cos \omega t$$

Mach-Zehnder Modulator

# Setup (實驗配置圖架構)



Power meter



Keithley 2400



# 預報問題

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- (1) 在非等向性晶體中，何謂單光軸晶體，和雙光軸晶體？
- (2) 請描述單光軸線性電光效應，折射率橢球在外加電場下的各方向折射率表示方式？（進一步用矩陣表示）

## 預報內容提醒

- 實驗名稱
- 實驗目的
- 實驗架構
- 實驗原理
- 預報題目